## NSN 5962-01-354-4135

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## **Body Length:** 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 550.0 milliwatts **Operating Tempurature Range:** -55.0/+150.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and electrostatic sensitive and monolithic and programmed and ultraviolet erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.6 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 45.00 nanoseconds access Memory Device Type: Eprom **Special Features:** 2k x 8uv erasable prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a Unit Of Measure: ---

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Demilitarization:

No

Fiig:

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